TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

2SK1529

High-Power Amplifier Application

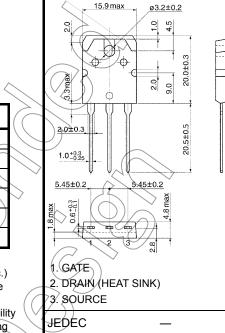
- High breakdown voltage
- : V_{DSS} = 180 V
- High forward transfer admittance : |Y_{fs}| = 4.0 S (typ.)
- Complementary to 2SJ200

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V _{DSS}	180	V
Gate-source voltage	V _{GSS}	±20	V
Drain current (Note 1)	۱ _D	10	Â
Drain power dissipation (Tc = 25° C)	PD	120	(W)
Channel temperature	T _{ch}	150	('c))
Storage temperature range	T _{stg}	-55 to 150	್

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Ensure that the channel temperature does not exceed 150°C:

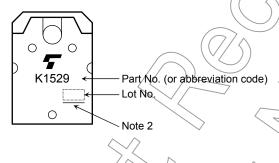


Weight: 4.6 g (typ.)

SC-65

2-16C1B

Marking



Note 2: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV

JEITA

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Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Electrical Characteristics (Ta = 25°C)

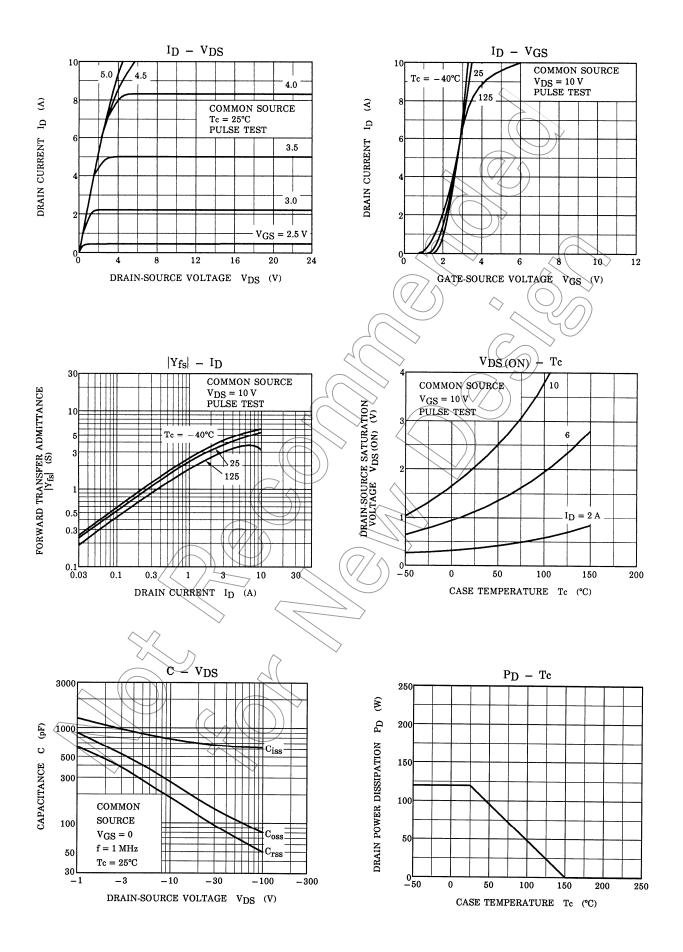
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain cut-off current	IDSS	V _{DS} = 180 V, V _{GS} = 0	_	_	1.0	mA
Gate leakage current	IGSS	V _{DS} = 0, V _{GS} = ±20 V	_	_	±0.5	μA
Drain-source breakdown voltage	V(BR) DSS	I _D = 10 mA, V _{GS} = 0	180	—	—	V
Drain-source saturation voltage	V _{DS (ON)}	I _D = 6 A, V _{GS} = 10 V	_	2.5	5.0	V
Gate-source cut-off voltage (Note 3)	V _{GS (OFF)}	V _{DS} = 10 V, I _D = 0.1 A	0.8	—	2.8	V
Forward transfer admittance	Y _{fs}	V _{DS} = 10 V, I _D = 3 A	—	4.0	—	S
Input capacitance	C _{iss}	V_{DS} = 30 V, V_{GS} = 0, f = 1 MHz	_	700	_	
Output capacitance	C _{oss}	V _{DS} = 30 V, V _{GS} = 0, f = 1 MHz	_	150	_	pF
Reverse transfer capacitance	C _{rss}	V_{DS} = 30 V, V_{GS} = 0, f = 1 MHz	_	90	_	

Note 3: V_{GS (OFF)} Classification 0: 0.8 to 1.6 Y: 1.4 to 2.8

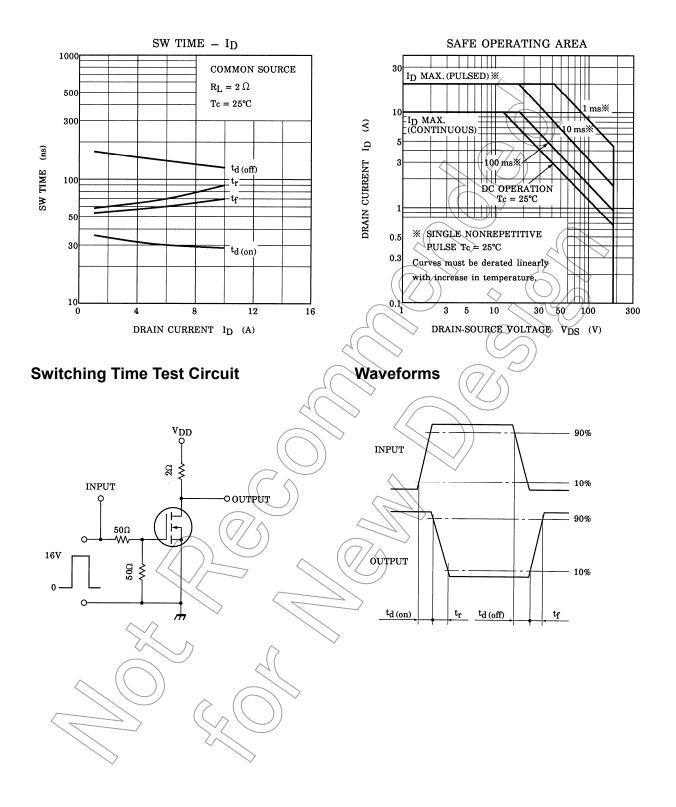
This transistor is an electrostatic-sensitive device. Please handle with caution.

Unit: mm

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